

# RBA190N15YAPF-6UA04

REXFET-1 N-Channel [Power MOSFET](#)

150 V - 190 A - 3.9 mΩ - TOLT for Automotive

## Description

The RBA190N15YAPF-6UA04 N-channel power MOSFET features REXFET-1 split-gate technology and is offered in a TOLT package. The TOLT package features top-side cooling for ultra-compact and optimal thermal performance. Renesas' REXFET-1 split gate technology is suitable for applications requiring low RDS(on) and switching capability for high-power and high-frequency applications.

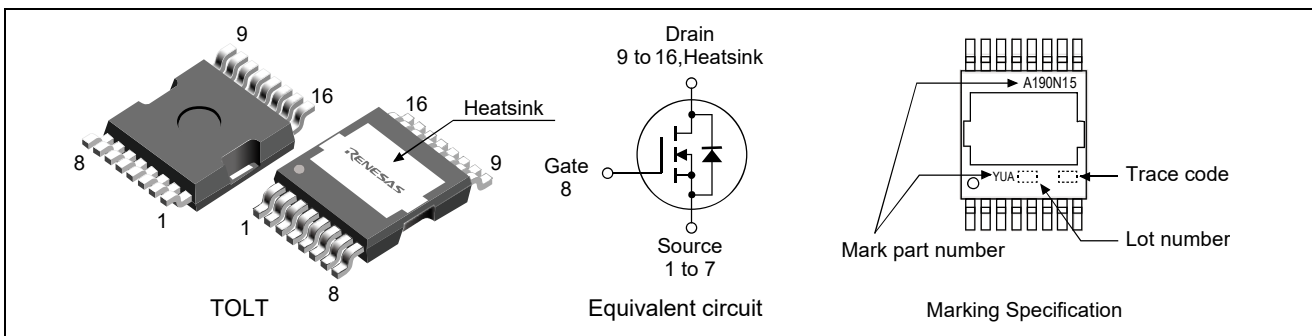
## Features

- Standard level gate drive voltage:  $V_{GS(th)} = 2.2$  to  $3.7$  V
- Super low on-state resistance:  $R_{DS(on)} = 3.9$  mΩ MAX.
- Low input capacitance
- Low thermal resistance
- 100% Avalanche tested
- AEC-Q101 qualified
- PPAP capable
- Pb-free lead plating: RoHS compliant
- MSL1 classified according to IPC/JEDEC J-STD-020

## Application

Small Traction (2-wheel, 3-wheel vehicle), 72 to 96 V load, Onboard charger, Charging station, Low voltage DC/DC,

## Outline



## Absolute Maximum Ratings

( $T_j = 25$  °C unless otherwise notice)

Item	Symbol	Ratings	Unit
Drain to Source Voltage	$V_{DSS}$	150	V
Gate to Source Voltage	$V_{GSS}$	±20	V
Continuous Drain Current	$I_D(T_c = 25^\circ C)$ <small>Note 2,6</small>	±190	A
	$I_D(T_c = 100^\circ C)$ <small>Note 2,6</small>	±135	A
Pulsed Drain Current	$I_D(pulse)$ <small>Note 1,2,3,6</small>	±760	A
Power Dissipation	$P_D$ <small>Note 1,6</small>	319	W
Operating and Storage Temperature	$T_j, T_{stg}$	-55 to 175	°C
Single Avalanche Current	$I_{AS}$ <small>Note 4</small>	65	A
Single Avalanche Energy	$E_{AS}$ <small>Note 4</small>	317	mJ

## Thermal Resistance

Item	Symbol	Min	Typ	Max	Unit
Junction to Case Thermal Resistance	$R_{th(j-c)}$ <sup>Note 6</sup>	—	—	0.47	°C/W
Junction to Ambient Thermal Resistance	$R_{th(j-a)}$ <sup>Note 5,6</sup>	—	—	40	°C/W

## Electrical Characteristics

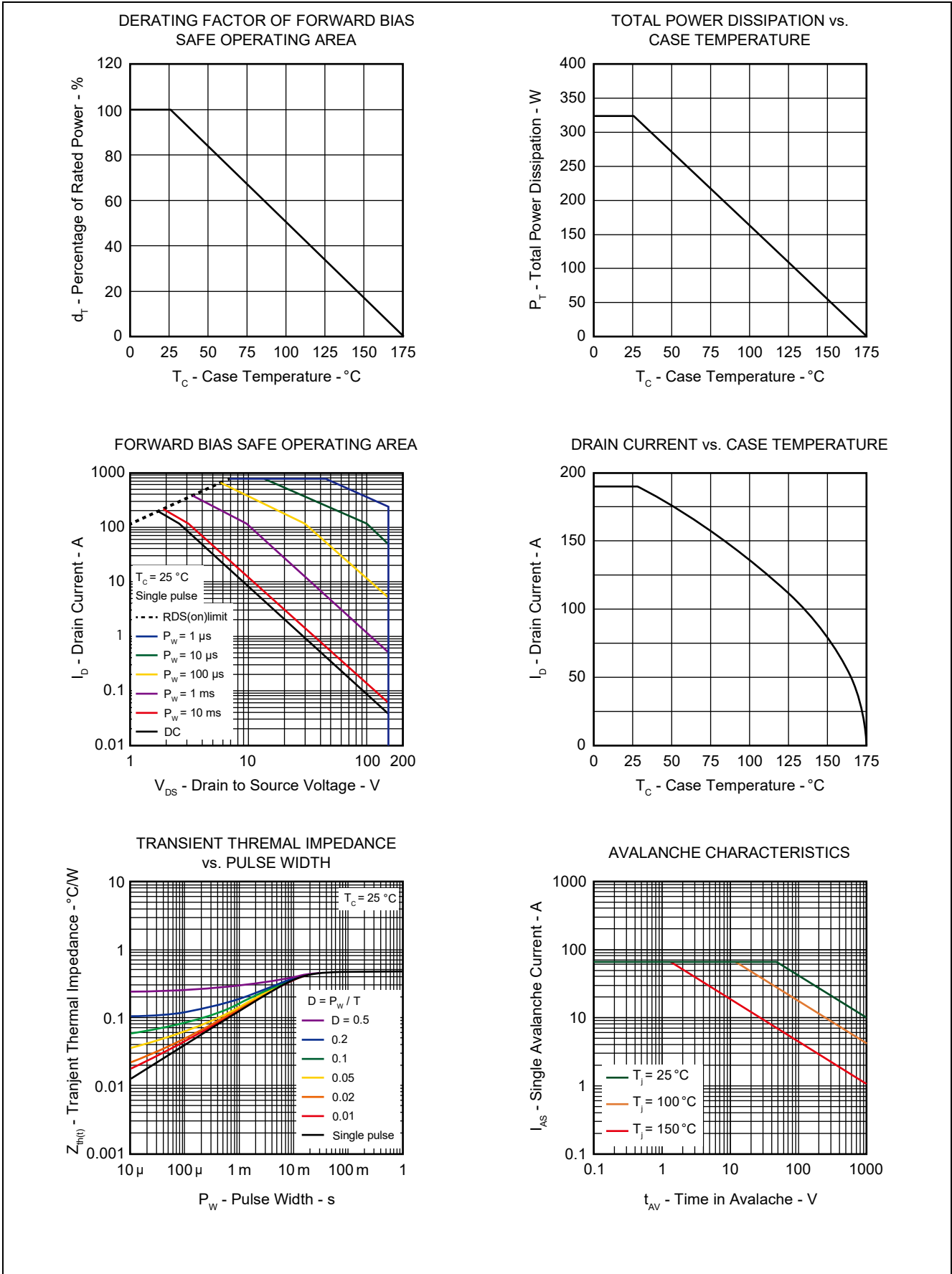
(T<sub>j</sub> = 25 °C unless otherwise notice)

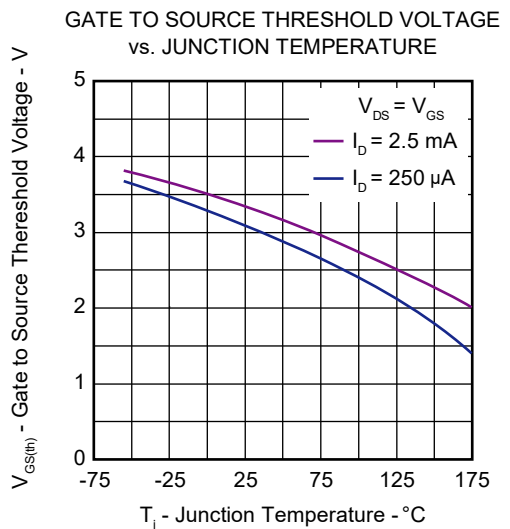
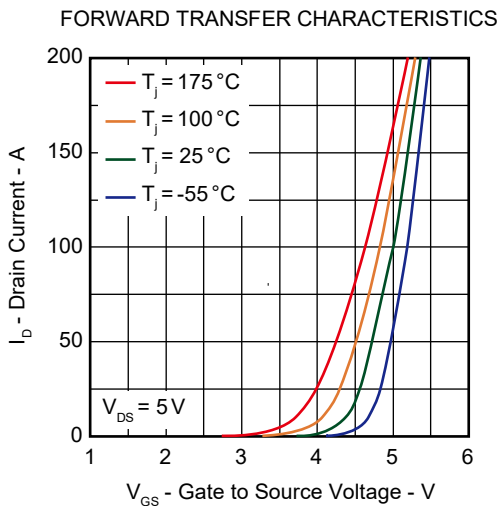
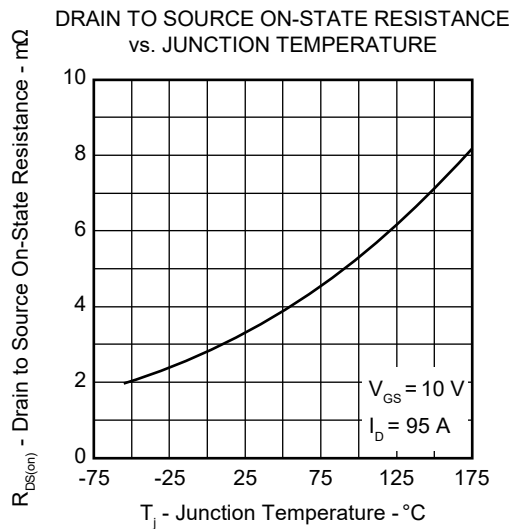
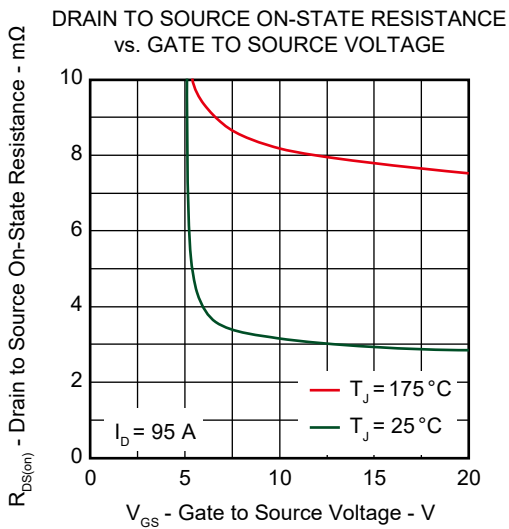
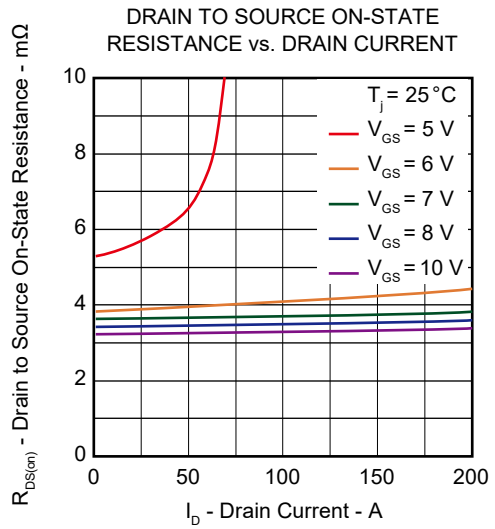
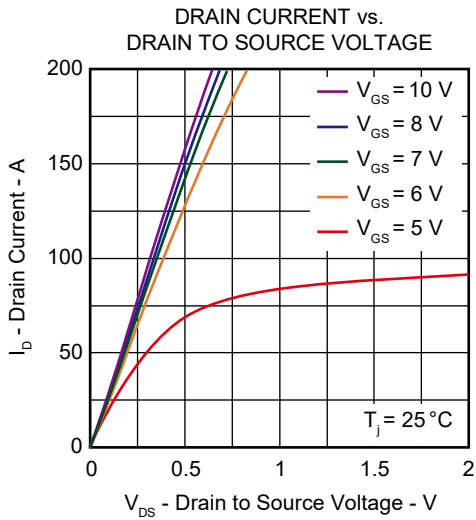
Item	Symbol	Min	Typ	Max	Unit	Test Conditions
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	—	—	1	μA	V <sub>DS</sub> = 150 V, V <sub>GS</sub> = 0 V
Gate Leakage Current	I <sub>GSS</sub>	—	—	±100	nA	V <sub>GS</sub> = ±20 V, V <sub>DS</sub> = 0 V
Gate to Source Threshold Voltage	V <sub>GS(th)</sub>	2.2	—	3.7	V	V <sub>DS</sub> = V <sub>GS</sub> , I <sub>D</sub> = 250 μA
Drain to Source On-state Resistance	R <sub>DS(on)</sub>	—	3.2	3.9	mΩ	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 95 A
Input Capacitance	C <sub>iss</sub>	—	5500	—	pF	V <sub>DS</sub> = 75 V, V <sub>GS</sub> = 0 V f = 100 kHz
Output Capacitance	C <sub>oss</sub>	—	1800	—	pF	
Reverse Transfer Capacitance	C <sub>rss</sub>	—	33	—	pF	
Gate resistance	R <sub>g</sub>	—	3.5	—	Ω	—
Turn-on Delay Time	t <sub>d(on)</sub>	—	30	—	ns	V <sub>DD</sub> = 75 V, I <sub>D</sub> = 50 A V <sub>GS</sub> = 10 V R <sub>G</sub> = 5 Ω
Rise Time	t <sub>r</sub>	—	15	—	ns	
Turn-off Delay Time	t <sub>d(off)</sub>	—	75	—	ns	
Fall Time	t <sub>f</sub>	—	15	—	ns	
Total Gate Charge	Q <sub>g</sub>	—	76	—	nC	V <sub>DD</sub> = 75 V, I <sub>D</sub> = 50 A V <sub>GS</sub> = 10 V
Gate to Source Charge	Q <sub>gs</sub>	—	28	—	nC	
Gate to Drain Charge	Q <sub>gd</sub>	—	13	—	nC	
Gate plateau voltage	V <sub>plateau</sub>	—	5.0	—	V	
Output Charge	Q <sub>oss</sub>	—	210	—	nC	V <sub>DS</sub> = 75 V, V <sub>GS</sub> = 0 V
Body Diode Forward Voltage	V <sub>F(S-D)</sub>	—	0.87	1.5	V	I <sub>F</sub> = 95 A, V <sub>GS</sub> = 0 V
Reverse Recovery Time	t <sub>rr</sub>	—	120	—	ns	I <sub>F</sub> = 50 A, V <sub>GS</sub> = 0 V
Reverse Recovery Charge	Q <sub>rr</sub>	—	400	—	nC	di/dt = 100 A/μs

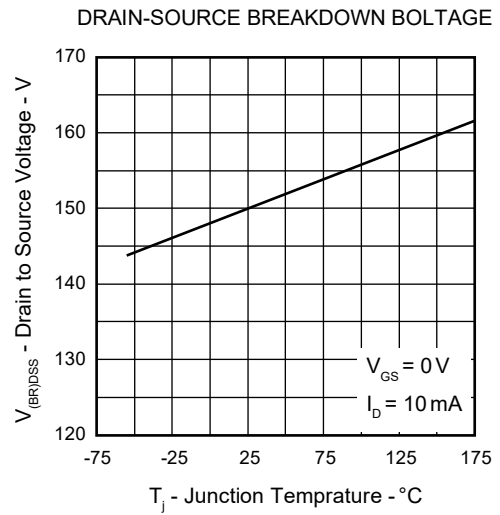
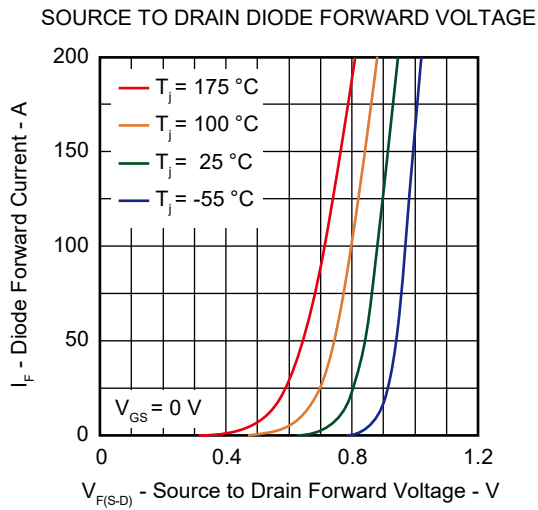
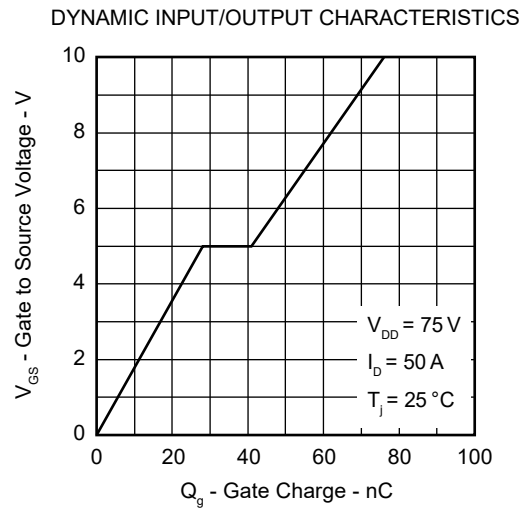
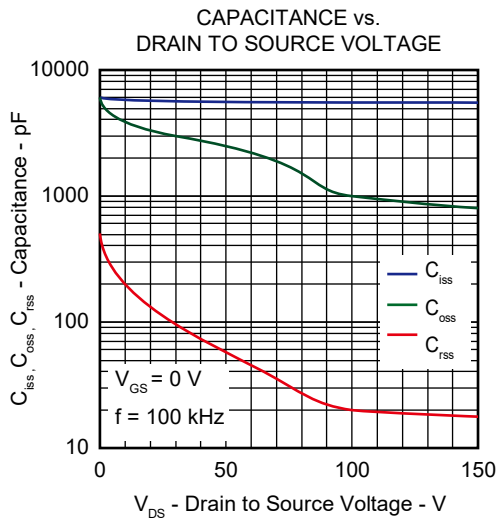
Note 1. T<sub>c</sub> = 25 °C

2. Value is limited by overall system design including PCB.
3. PW ≤ 10 μs
4. L = 100 μH, V<sub>DD</sub> = 50 V, R<sub>G</sub> = 25 Ω
5. Device on 40 mm x 40 mm x 1.5 mm epoxy PCB FR4. (2 oz Cu pad.)
6. Defined by design. Not subject to production test.

### Typical Characteristics



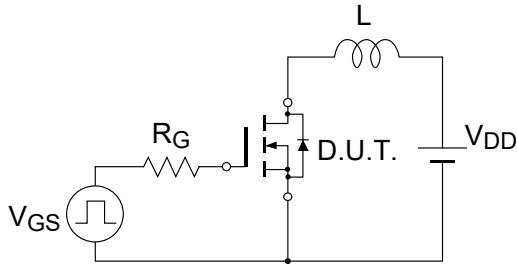




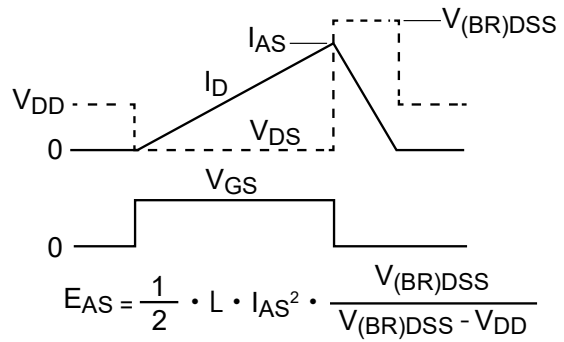
**Test Circuit**

**Avalanche**

Test Circuit

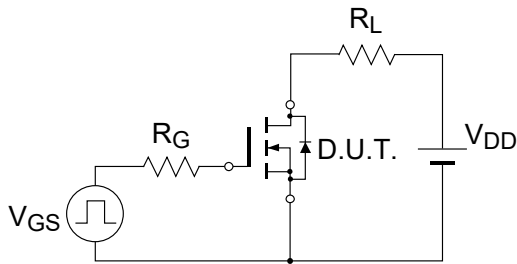


Waveform

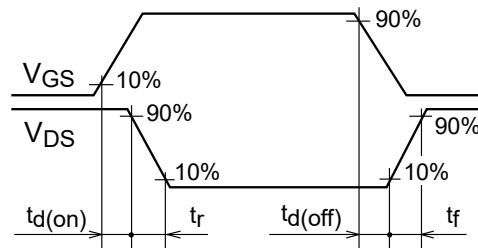


**Switching Time**

Test Circuit

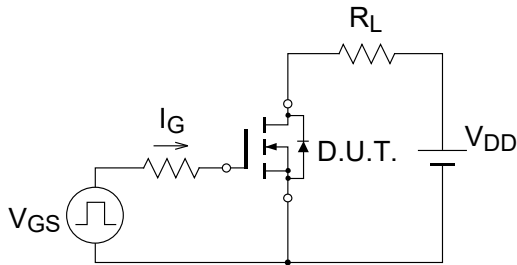


Waveform

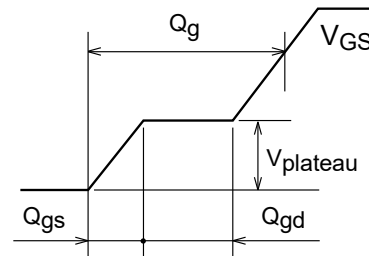


**Gate Charge**

Test Circuit

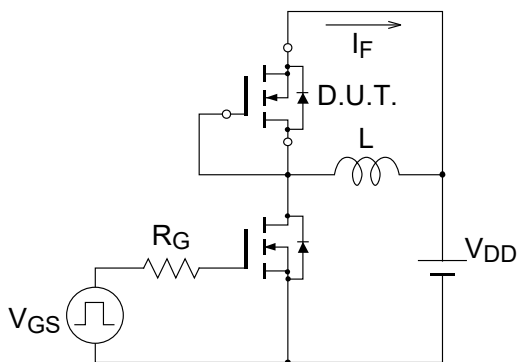


Waveform

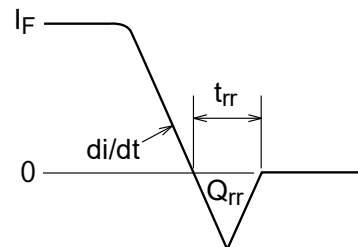


**Reverse Recovery**

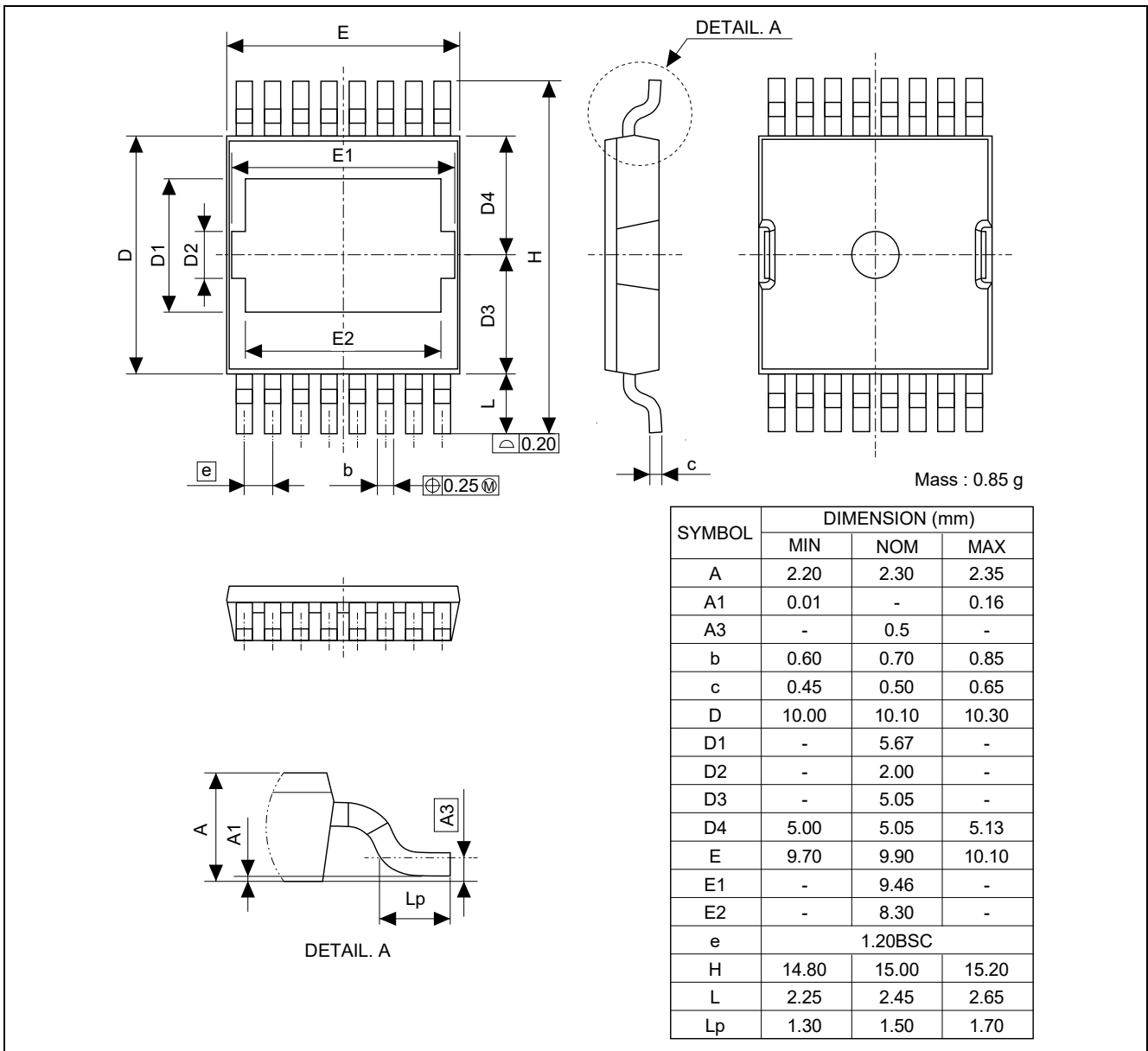
Test Circuit



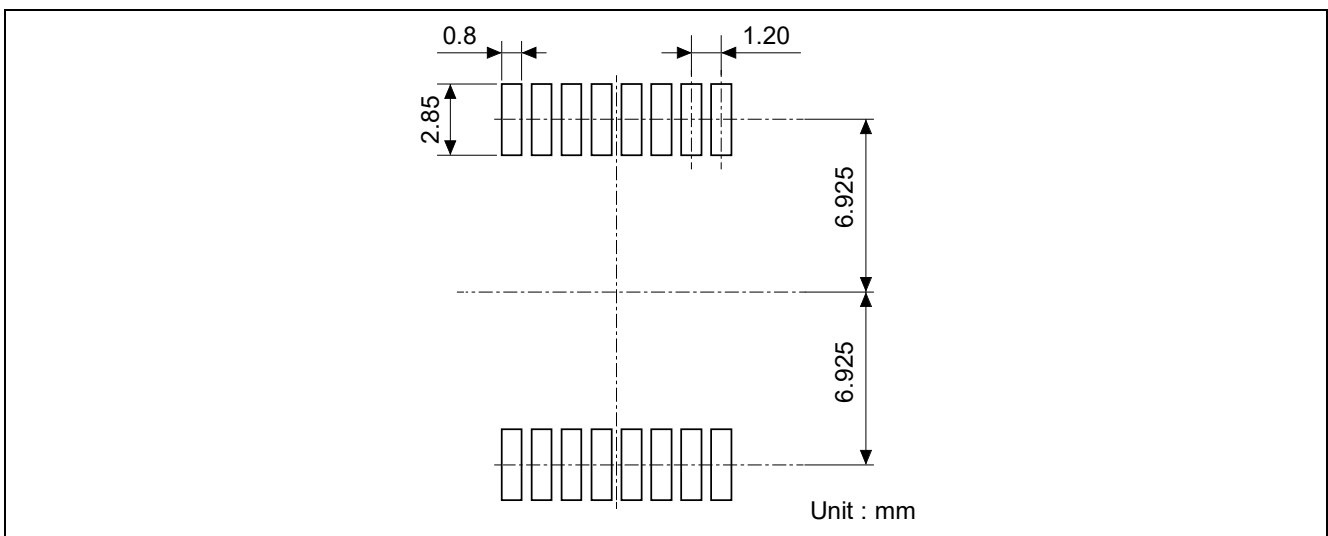
Waveform



### Package Dimensions



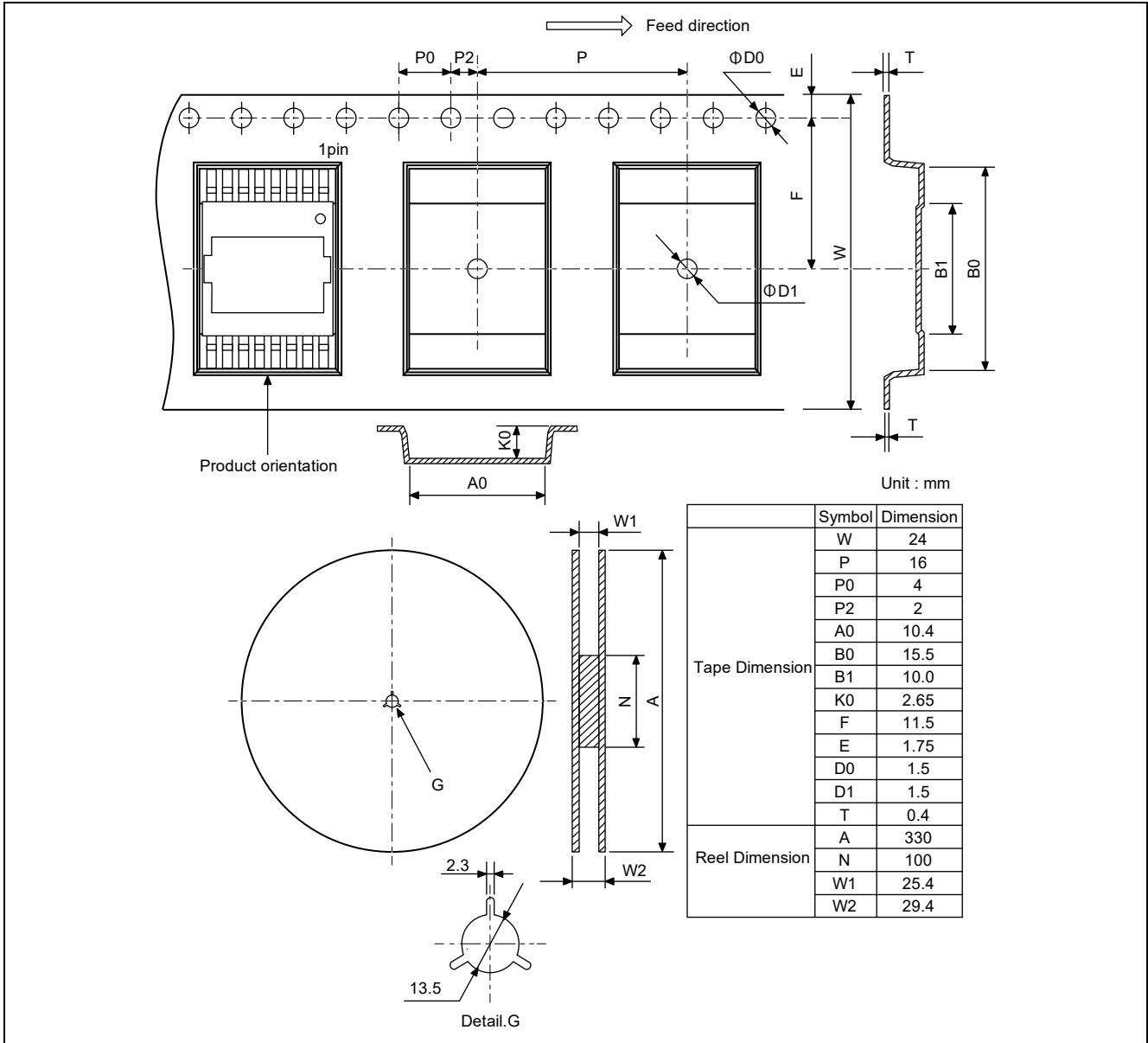
### Mount pad



### Ordering Information

Part No.	Packing	Quantity
RBA190N15YAPF-6UA04#KB0	Taping	1300 pcs/reel

### Packing Specification



Remark: Strong electric field, when exposed to this device, can cause destruction of the gate oxide and ultimately degrade the device operation. Steps must be taken to stop generation of static electricity as much as possible, and quickly dissipate it once, when it has occurred.



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